

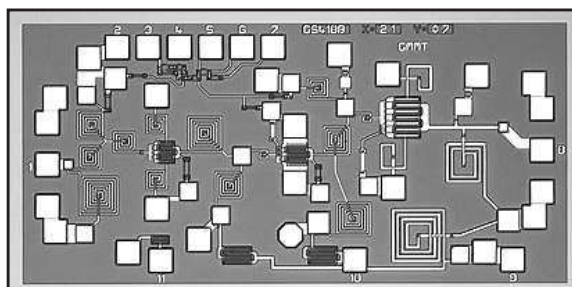
## MMIC Driver Amplifier, 5-6GHz

The **P35-4720-000-200** is a high performance Gallium Arsenide Driver Amplifier MMIC. It is primarily intended for wireless applications in the 5-6 GHz bandwidth such as U-NII (Unlicensed National Information Infrastructure) and HIPERLAN (High Performance Local Area Network). The three-stage amplifier requires plus and minus 5V power supplies. Also incorporated into the design is the ability to switch between two gain states, High and Low Gain, as well as a chip standby mode which typically draws 0.1mA. In addition the design has been optimised for the effects of a single bondwire at both the input and output.

The die is fabricated using Bookham Technology's F20 Gallium Arsenide MESFET MMIC process and is fully protected using Silicon Nitride passivation for excellent performance and reliability.

### Features

- 24 dB Gain typical
- F20 MESFET Technology
- 21dBm Output Power Typ @6V
- High & Low Gain States
- PAE (Max) 25%



**Electrical Performance**

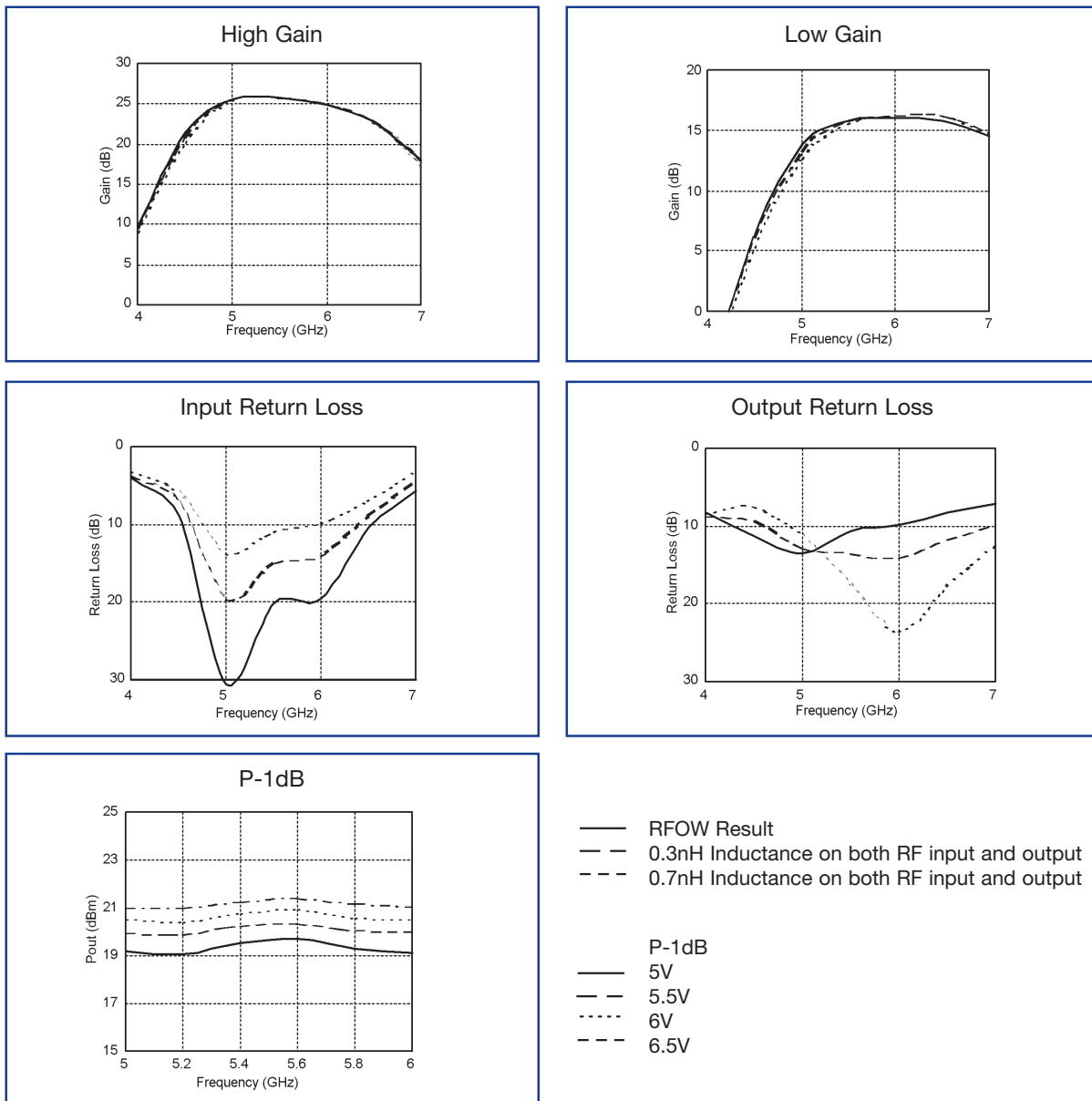
Ambient temperature = 22 ±3 ° C, ZO = 50 Ω, Vgg = -5V, Vdd = +5V

Parameter	Conditions	Min	Typ	Max	Units
Small signal gain 1,2	5GHz - 6GHz	22	24	-	dB
Gain Flatness1,2	5GHz - 6GHz	-	±1.0	-	dB
Input Return Loss1,2	5GHz - 6GHz	10	20	-	dB
Output Return Loss1,2	5GHz - 6GHz	8	12	-	dB
Noise Figure1,2	5GHz - 6GHz	-	4.5	-	dB
P-1dB Output Power1,2	5GHz - 6GHz	-	19	-	dBm
TOI1,2	5.5GHz	-	29	-	dBm
Supply current (Idd) 2	Disabled	-	0.1	1	mA
Supply current (Idd) 1,2	Enabled (No RF)	-	118	-	mA

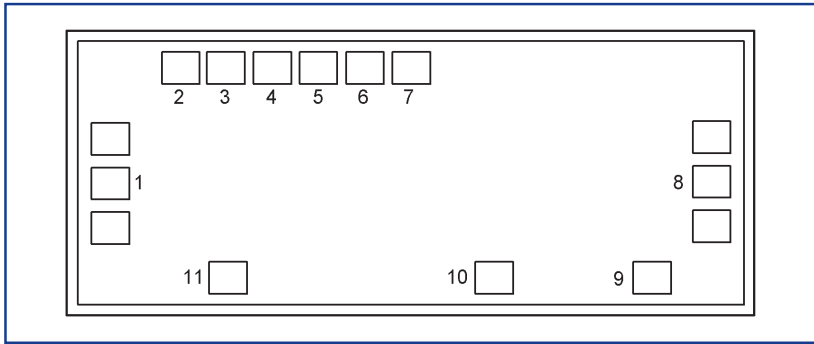
**Notes**

1. High Gain State
2. All Parameters Measured on Wafer

**Typical Performance at 22 ° C**



### Die Outline



Die size: 1.34 x 2.71 mm  
 DC Bond pad size: 120  $\mu$ m square  
 RF Bond pad size: 120  $\mu$ m square  
 Die thickness: 200  $\mu$ m

### Pad Details

Pad	Function
1	RF Input
2	NC
3	Vgg = -5V
4	Vg1 Sense N/C
5	Vg2 Vg3 Sense N/C
6	High/ Low Enable
7	High/ Low Enable
8	RF Output
9	Gnd
10	Vdd = +5V
11	Gnd

### Truth Table

Pad 6	Pad 7	Function
0V	O/C	High Gain Enabled
O/C	0V	Low Gain Enabled
-5V	0V	Amplifier Disabled

### Absolute maximum Ratings

Max Vd +7.0V  
 Max Vgg -5.0V  
 Operating temperature -55°C to 125°C  
 Storage temperature -65°C to +150°

### Ordering Information

P35-4720-000-200



### MMICS

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